



## Power Bridge Rectifiers

### SKD 25

#### Features

- Square plastic case with isolated metal base plate and fast-on connectors
- Blocking voltage to 1600 V
- High surge current
- Easy chassis mounting
- UL recognized, file no. E 63 532

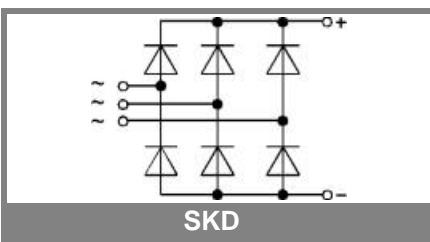
#### Typical Applications

- Three phase rectifier for power supplies
- Input rectifiers for variable frequency drives
- Rectifier for DC motor field supplies
- Battery charger rectifiers
- Recommended snubber network: RC: 50 Ω, 0.1 μF ( $P_R = 1 W$ )

- 1) Freely suspended or mounted on an insulator
- 2) Mounted on a painted metal sheet of min. 250 x 250 x 1 mm

$V_{RSM}, V_{RRM}$ V	$V_{VRMS}$ V	$I_D = 20 A (T_c = 73 °C)$ Types	$C_{max}$ μF	$R_{min}$ Ω
200		SKD 25/02		0,15
400		SKD 25/04		0,3
800		SKD 25/08		0,7
1200		SKD 25/12		1
1400		SKD 25/14		1,2
1600		SKD 25/16		1,5

Symbol	Conditions	Values	Units
$I_D$	$T_a = 45 °C$ , isolated <sup>1)</sup>	3,5	A
	$T_a = 45 °C$ , chassis <sup>2)</sup>	12	A
$I_{DCL}$	$T_a = 45 °C$ , isolated <sup>1)</sup>	3,5	A
	$T_a = 45 °C$ , chassis <sup>2)</sup>	12	A
$I_{FSM}$	$T_{vj} = 25 °C$ , 10 ms	370	A
	$T_{vj} = 150 °C$ , 10 ms	320	A
$i^2t$	$T_{vj} = 25 °C$ , 8,3 ... 10 ms	680	A <sup>2</sup> s
	$T_{vj} = 150 °C$ , 8,3 ... 10 ms	500	A <sup>2</sup> s
$V_F$	$T_{vj} = 25 °C$ , $I_F = 150 A$	max. 2,2	V
$V_{(TO)}$	$T_{vj} = 150 °C$	0,85	V
$r_T$	$T_{vj} = 150 °C$	12	mΩ
$I_{RD}$	$T_{vj} = 25 °C$ , $V_{RD} = V_{RRM}$	300	μA
$I_{RD}$	$T_{vj} = 150 °C$ , $V_{RD} = V_{RRM}$	5	mA
$t_{rr}$	$T_{vj} = 25 °C$	10	μs
$f_G$		2000	Hz
$R_{th(j-a)}$	isolated <sup>1)</sup>	15	K/W
	chassis <sup>2)</sup>	4,7	K/W
$R_{th(j-c)}$	total	1,75	K/W
$R_{th(c-s)}$	total	0,15	K/W
$T_{vj}$		- 40 ... + 150	°C
$T_{stg}$		- 55 ... + 150	°C
$V_{isol}$	a. c. 50 ... 60 Hz; r.m.s.; 1 s / 1 min.	3000 / 2500	V~
$M_s$	to heatsink	2 ± 15 %	Nm
$M_t$			Nm
m		26	g
$F_u$		20	A
Case		G 11a	



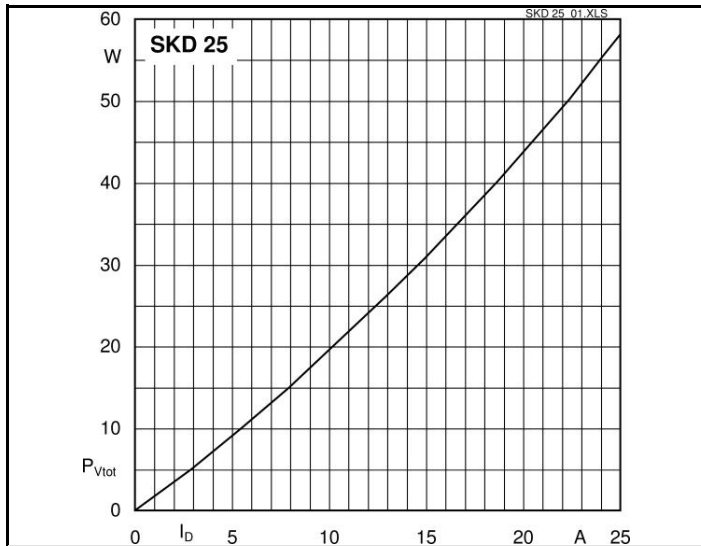


Fig. 3L Power dissipation vs. output current

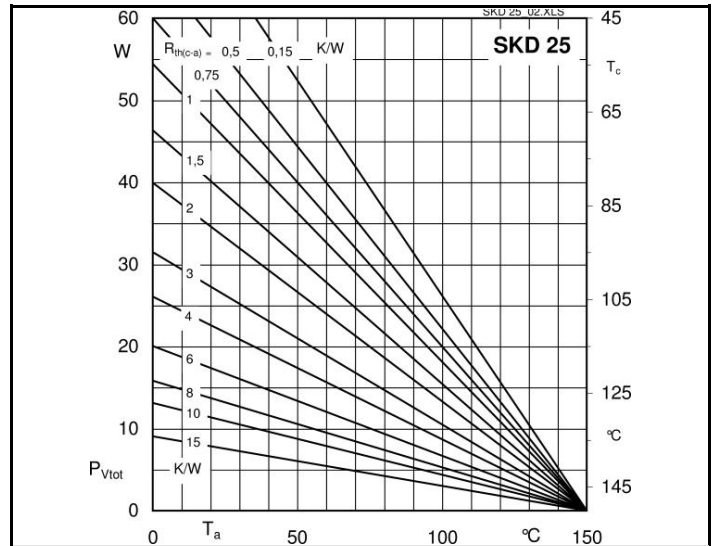


Fig. 3R Power dissipation vs. case temperature

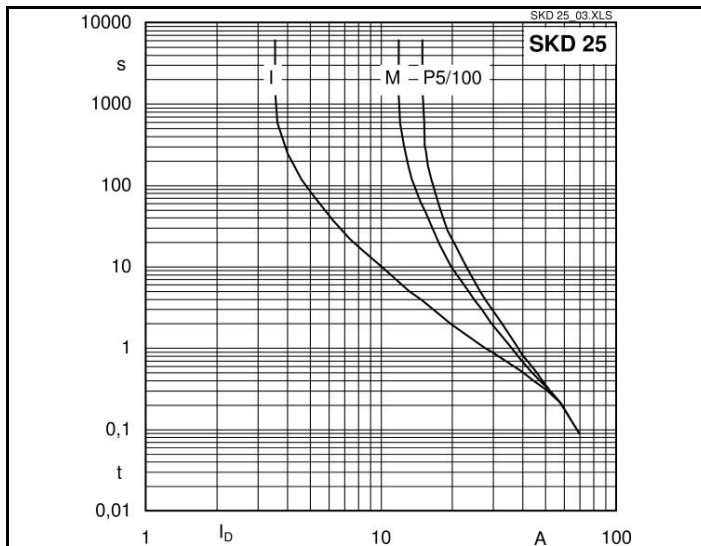


Fig. 6 Rated overload characteristics vs. time

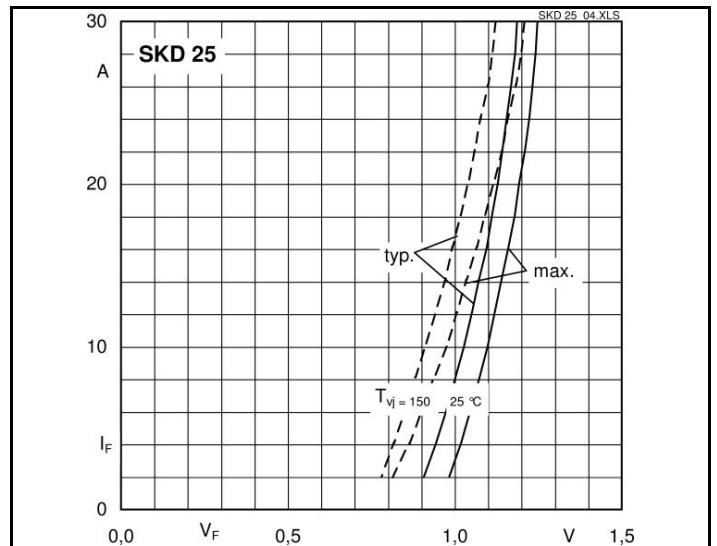
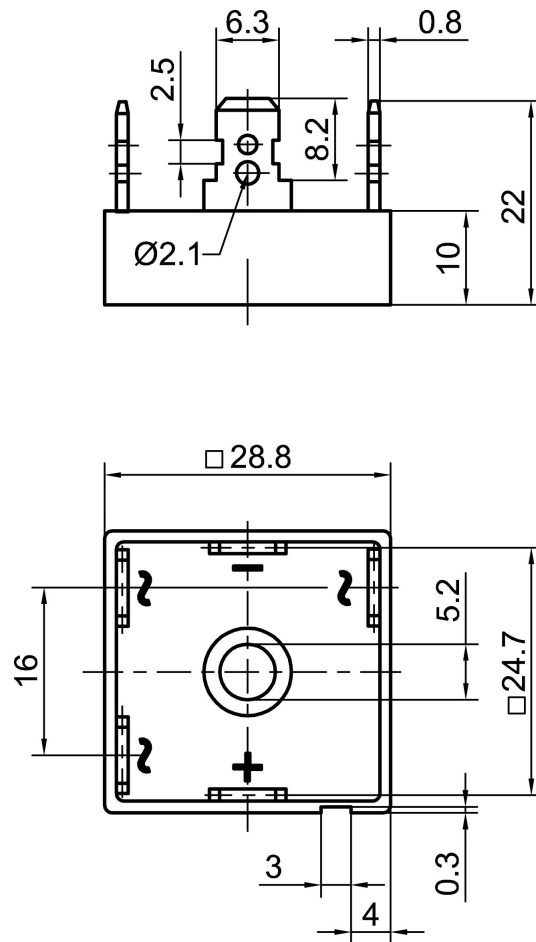


Fig. 9 Forward characteristics of a diode arm



Case G 11a

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